



#### 4-Bit Bi-directional Level Shifter with Automatic Direction Controller

#### **Features**

- → 1.2V to 3.6V on A Port and 1.65V to 5.5V on B Port ( $V_{CCA} \le V_{CCB}$ )
- → V<sub>CC</sub> Isolation Feature If Either V<sub>CC</sub> Input Is at GND, All Outputs Are in the High-Impedance State
- → OE Input Circuit Referenced to V<sub>CCA</sub>
- → Low Power Consumption, 5-µA Max I<sub>CC</sub>
- → I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- → Latch-Up Performance Exceeds 100mA Per JESD 78, Class II
- → ESD Protection Exceeds JESD 22

#### A Port

- 2500-V Human-Body Model (A114-F)
- 200-V Machine Model (A115-A)
- 1500-V Charged-Device Model (C101D)

#### **B** Port

- 15-kV Human-Body Model (A114-F)
- 200-V Machine Model (A115-A)
- · 1500-V Charged-Device Model (C101D)
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- → Packaging (Pb-free & Green):
  - 14-pins, 3.5x3.5 TQFN (ZB)

### **Description**

This 4-bit non-inverting translator uses two separate configurable power-supply rails. The A port is designed to track  $V_{\rm CCA}$ .  $V_{\rm CCA}$  accepts any supply voltage from 1.2V to 3.6V. The B port is designed to track  $V_{\rm CCB}$ .  $V_{\rm CCB}$  accepts any supply voltage from 1.65V to 5.5V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5V voltage nodes.  $V_{\rm CCA}$  should not exceed  $V_{\rm CCB}$ .

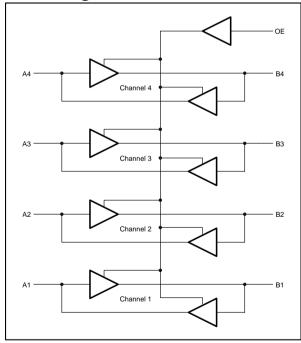
When the output-enable (OE) input is low, all outputs are placed in the high-impedance state.

The PI4ULS5V104 is designed so that the OE input circuit is supplied by  $V_{\text{CCA}}$ .

This device is fully specified for partial-power-down applications using  $I_{\rm off}$ . The  $I_{\rm off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

### **Block Diagram**



#### Notes

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

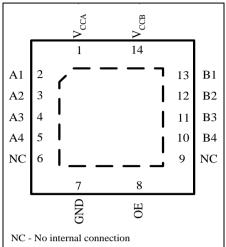
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





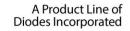
# **Pin Configuration**



**Pin Description** 

Pin Name	Pin Description
$V_{CCA}$	A-port supply voltage 1.2 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> .
A1	Input/output 1. Referenced to V <sub>CCA</sub> .
A2	Input/output 2. Referenced to V <sub>CCA</sub> .
A3	Input/output 3. Referenced to V <sub>CCA</sub> .
A4	Input/output 4. Referenced to V <sub>CCA</sub> .
GND	Ground
OE	3-State output. Pull OE low to place all outputs in 3-state mode. Referenced to V <sub>CCA</sub> .
B4	Input/output 4. Referenced to V <sub>CCB</sub> .
В3	Input/output 3. Referenced to $V_{CCB}$ .
B2	Input/output 2. Referenced to V <sub>CCB</sub> .
B1	Input/output 1. Referenced to V <sub>CCB</sub> .
$V_{CCB}$	B-port supply voltage 1.65 V $\leq$ V <sub>CCB</sub> $\leq$ 5.5 V.







# Maximum Ratings\*1

			Min.	Max.	Unit
$V_{CCA}$	Supply voltage range		-0.5	4.6	V
$V_{CCB}$	Supply voltage range		-0.5	6.5	V
$V_{\rm I}$	Input voltage range	A port	-0.5	4.6	V
VI	input voltage range	B port	-0.5	6.5	v
V	Voltage range applied to any output in the high-impedance	A port	-0.5	4.6	V
$V_{O}$	or power-off state	B port	-0.5	6.5	V
V	Voltage range applied to any output in the high or low	A port	-0.5	$V_{CCA} + 0.5$	V
$V_{\rm o}$	state*2	B port	-0.5	$V_{CCB} + 0.5$	· ·
$I_{IK}$	Input clamp current, $V_I < 0$		-	-50	mA
$I_{OK}$	Output clamp current, V <sub>O</sub> < 0		-	-50	mA
$I_{O}$	Continuous output current	-	±50	mA	
$I_{O}$	Continuous current through V <sub>CCA</sub> , V <sub>CCB</sub> , or GND		-	±100	mA
$T_{ m stg}$	Storage temperature range		-65	150	$^{\circ}\mathbb{C}$

<sup>\*1</sup> Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Recommend Operation Conditions $^{(1)(2)}$

Parameter	Description		V <sub>CCA</sub>	V <sub>CCB</sub>	Min.	Max.	Unit
V <sub>CCA</sub>	Supply voltage		-	-	1.2	3.6	V
$V_{CCB}$	Supply tolkings		-	-	1.65	5.5	·
		Data inputs	1.2V to	1.65V to	$V_{\text{CCI}}^*$	$V_{CCI}$	
$V_{IH}$	High-level input voltage	Data inputs	3.6V	5.5V	$0.65^{(3)}$	, cci	V
V IH	riigii-ievei iiiput voitage	OE input	1.2V to	1.65V to	$V_{CCA}$ *	5.5	•
		OE IIIput	3.6V	5.5V	0.7	3.3	
		Data in a to	1.2V to	1.65V to	0	V <sub>CCI</sub> *	
37	The design of the co	Data inputs		5.5V	0	$0.35^{(3)}$	V
$V_{ m IL}$	Low-level input voltage	OF the 4	1.2V to	1.65V to	0	V <sub>CCA</sub> *	V
		OE input	3.6V	5.5V	0	0.3	
37	Voltage range applied to any output in the	A port	1.2V to	1.65V to	0	3.6	V
$V_{O}$	high-impedance or power-off state	B port	3.6V	5.5V	0	5.5	ľ
		A port	1.2V to	1.65V to		40	
		inputs	3.6V	5.5V	-	40	
A . / A	Town of America's an original of Co. 11 made			1.65V to		40	/\.7
$\triangle t/\triangle v$	Input transition rise or fall rate	B port	1.2V to	3.6V	-	40	ns/V
		inputs	3.6V	4.5V to		20	1
		_		5.5V	-	30	
$T_A$	Operating free-air temperature		-	-	-40	85	$^{\circ}$ C

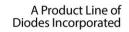
<sup>(1)</sup> The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V<sub>CCI</sub> or both at GND.

<sup>\*2</sup> The value of  $V_{\text{CCA}}$  and  $V_{\text{CCB}}$  are provided in the recommended operating conditions table.

<sup>(2)</sup>  $V_{CCA}$  must be less than or equal to  $V_{CCB}$  and must not exceed 3.6 V.

<sup>(3)</sup>  $V_{\text{CCI}}$  is the supply voltage associated with the input port.







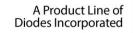
# DC Electrical Characteristics (1)(2)

Da	rameter	Test Conditions	<b>X</b> 7	<b>X</b> 7		$T_A = 25^{\circ}C$	ļ	-40 to	85℃	Unit
Pal	rameter	Test Conditions	$V_{CCA}$	$\mathbf{V}_{\mathbf{CCB}}$	Min	Тур	Max	Min	Max	Unit
	V	I <sub>OH</sub> = -20μA	1.2V		1.0	1.1	1.2	-	ı	V
	$ m V_{OHA}$	$I_{OH} = -20\mu A$	1.4V to 3.6V	-	-	-	-	V <sub>CCA</sub> - 0.4	-	•
	V <sub>OLA</sub>	$I_{OL} = 20 \mu A$	1.2V 1.4V to 3.6V	-	0.0	0.09	0.4	-	0.4	V
	$V_{OHB}$	$I_{OH} = -20 \mu A$	-	1.65V to 5.5V	-	-	-	V <sub>CCB</sub> - 0.4		V
	$V_{OLB}$	$I_{OL} = 20 \mu A$	-	1.65V to 5.5V	-	-	-	-	0.4	V
$I_{I}$	OE	$V_I = V_{CCI}$ or GND	1.2 to 3.6V	1.65V to 5.5V	-	-	±1	-	±2	μΑ
т	A port	$V_{\rm I}$ or $V_{\rm O} = 0$ to $3.6 \text{V}$	0V	0V to 5.5V	-	-	±1	-	±2	
$I_{ m off}$	B port	$V_{\rm I}$ or $V_{\rm O} = 0$ to 5.5V	0 to 3.6V	0V	-	-	±1	-	±2	μA
$I_{OZ}$	A or B		1.2 to 3.6V	1.65V to 5.5V	-	-	±1	-	±2	μΑ
			1.2V	1.65V to 5.5V	0.0	0.06	5.0	-	-	
	т	$V_{I} = V_{CCI}$ or	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	5	μA
	$I_{CCA}$	GND, $Io = 0$	3.6V	0V 5.5V	ı	-	-	-	2	μΑ
			0V		-	-	-	-	-2	
			1.2V	1.65V to 5.5V	0	2.3	5	-	-	
	$I_{CCB}$	$V_I = V_{CCI} \text{ or } $ 1.4V		1.65V to 5.5V	-	-	-	-	5	μΑ
	1CCB	GND, $Io = 0$	3.6V	0V	-	-	-	-	-2	μΑ
			0V	5.5V	-	-	-	-	2	
Las	$I_A + I_{CCB}$	$V_{I} = V_{CCI}$ or	1.2V	1.65V to 5.5V	0.0	2.4	10	-	-	μA
100	A 1 CCB	GND, $Io = 0$	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	8	μπ
	$I_{CCZA}$	$V_I = V_{CCI}$ or $GND$ , $Io = 0$ , $OE$	1.2V	1.65V to 5.5V	0.0	0.05	0.4	-	-	μA
	-CCZA	= GND	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	5	pu 1
	$I_{CCZB}$	$V_I = V_{CCI}$ or $GND$ , $Io = 0$ , $OE$	1.2V	1.65V to 5.5V	0.0	2.3	5.0	-	-	μA
		= GND	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	5	·
Ci	OE	-	1.2 to 3.6V	1.65V to 5.5V	-	3	-	-	4	pF
Cio	A port B port	-	1.2 to 3.6V	1.65V to 5.5V	-	5 11	-	-	6 14	pF
	D Port			1	_	1.1	_	_	17	

<sup>(1)</sup>  $V_{\text{CCI}}$  is the supply voltage associated with the input port.

<sup>(2)</sup>  $V_{\text{CCO}}$  is the supply voltage associated with the output port.







### **AC Electrical Characteristics**

## **Timing requirements**

a.  $T_A = 25^{\circ}C$ ,  $V_{CCA} = 1.2V$ 

			$V_{CCB} = 1.8V$	$V_{CCB} = 2.5V$	$V_{CCB} = 3.3V$	$V_{CCB} = 5V$	Unit
			Тур.	Тур.	Тур.	Тур.	UIII
	Data rate		20	20	20	20	Mbps
$t_{\mathrm{W}}$	t <sub>w</sub> Pulse duration Data inputs		50	50	50	50	ns

b.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.5 \pm 0.1 \text{V}$ 

			$V_{CCB}$ =1.8±0.15V		$V_{CCB}=2.5\pm0.2V$		$V_{CCB}=3.3\pm0.3V$		$V_{CCB}=5\pm0.5V$		Unit
				Max	Min	Max	Min	Max	Min	Max	Unit
	Data rate		-	40	-	40	-	40	-	40	Mbps
$t_{\mathrm{W}}$	t <sub>W</sub> Pulse duration Data inputs		25	-	25	-	25	-	25	-	ns

c.  $T_A = 25$ °C,  $V_{CCA} = 1.8 \pm 0.15$ V

			$V_{CCB} = 1.8 \pm 0.15 V$		$V_{CCB}=2.5\pm0.2V$		$V_{CCB}=3.3\pm0.3V$		$V_{CCB}=5\pm0.5V$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	Unit
	Data rate		-	60	-	60	-	60	-	60	Mbps
$t_{\mathrm{W}}$	t <sub>w</sub> Pulse duration Data inputs		17	-	17	-	17	-	17	=	ns

d.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 2.5 \pm 0.2 \text{V}$ 

			$V_{CCB}$ =2.5±0.2V		$V_{CCB}=3$	.3±0.3V	$V_{CCB}=$	Unit	
			Min	Max	Min	Max	Min	Max	Omt
	Data rate		-	100	-	100	-	100	Mbps
t <sub>W</sub> Pulse Data inputs		10	-	10	-	10	-	ns	

e.  $T_A = 25^{\circ}C$ ,  $V_{CCA} = 3.3 \pm 0.3V$ 

			$V_{CCB}=3$	3.3±0.3V	$V_{CCB}=$	T 1 24	
			Min	Max	Min	Max	Unit
	Data rate		-	100	-	100	Mbps
$t_{\mathrm{W}}$	10	-	10	-	10	-	ns

# **Switching characteristics**

a.  $T_A = 25^{\circ}C$ ,  $V_{CCA} = 1.2V$ 

Parameter	From	To	$V_{CCB}=1.8V$	$V_{CCB}$ =2.5 $V$	$V_{CCB}=3.3V$	$V_{CCB}=5V$	Unit		
rarameter	(Input)	(Output)	Тур.	Тур.	Тур.	Тур.	Unit		
+	A	В	6.9	5.7	5.3	5.5	200		
$t_{ m pd}$	В	A	7.4	6.4	6	5.8	ns		
+	OE	A	0.2	0.2	0.2	0.2	110		
t <sub>en</sub>	OE	В	0.2	0.2	0.2	0.2	μs		
+	OE	A	0.4	0.4	0.4	0.4			
$t_{\mathrm{dis}}$	OE	В	0.2	0.2	0.2	0.2	μs		
$t_{rA}, t_{fA}$	-	ise and fall mes	4.2	4.2	4.2	4.2	ns		
$t_{rB},t_{fB}$	B-port rise and fall times		2.1	1.5	1.2	1.1	ns		
t <sub>SK(O)</sub>	Channel-to-channel skew		fav.(a)		0.5	0.5	0.5	1.4	ns
Max data rate		-	20	20	20	20	Mbps		





b.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.5 \pm 0.1 \text{V}$ 

Parameter	From	To	$V_{CCB}=1$ .	8±0.15V	$V_{CCB} = 2$	2.5±0.2V	$V_{CCB}=3.3\pm0.3V$		$V_{CCB} = 5 \pm 0.5 V$		Unit
Parameter	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Unit
+	A	В	1.4	12.9	1.2	10.1	1.1	10	0.8	9.9	na
$t_{ m pd}$	В	A	0.9	14.2	0.7	12	0.4	11.7	0.3	13.7	ns
4	OE	A	-	0.5	-	0.5	-	0.5	-	0.5	
t <sub>en</sub>	OE	В	-	0.5	-	0.5	-	0.5	-	0.5	μs
4	OE	A	-	0.5	-	0.5	-	0.5	-	0.5	
$t_{\mathrm{dis}}$	OE	В	-	0.5	-	0.5	-	0.5	-	0.5	μs
$t_{rA}, t_{fA}$		ise and fall mes	1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
$t_{rB},t_{fB}$		ise and fall mes	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t <sub>SK(O)</sub>		-to-channel kew	-	0.5	-	0.5	-	0.5	-	0.5	ns
Max data rate		•	40	-	40	-	40	-	40	=.	Mbps

### c. $T_A = 25$ °C, $V_{CCA} = 1.8 \pm 0.15 V$

Danamatan	From	To	$V_{CCB}=1$ .	8±0.15V	$V_{CCB}=2$	.5±0.2V	$V_{CCB}=3$	.3±0.3V	V <sub>CCB</sub> =	5±0.5V	Unit
Parameter	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4	A	В	1.6	11	1.4	7.7	1.3	6.8	1.2	6.5	<b>n</b> c
$t_{ m pd}$	В	A	1.5	12	1.3	8.4	1	7.6	0.9	7.1	ns
4	OE	A	-	0.3	ı	0.25		0.25	ı	0.25	
t <sub>en</sub>	OE	В	-	0.3	1	0.25		0.25	ı	0.25	μs
+	OE	A	-	0.5	1	0.5		0.5	ı	0.5	110
$t_{ m dis}$	OE	В	-	0.5	1	0.5		0.5	ı	0.5	μs
$t_{rA}, t_{fA}$		ise and fall mes	1	4.2	1	4.1	1	4.1	1	4.1	ns
$t_{rB}, t_{fB}$	-	ise and fall mes	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t <sub>SK(O)</sub>		-to-channel kew	-	0.5	ı	0.5	-	0.5	ı	0.5	ns
Max data rate			60	-	60	-	60	-	60	=	Mbps

### d. $T_A = 25^{\circ}C$ , $V_{CCA} = 2.5 \pm 0.2V$

Parameter	From	To	$V_{CCB}$ =2.5±0.2V		$V_{CCB}$ =3.3±0.3V		$V_{CCB}=5\pm0.5V$		T I 24	
Parameter	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Unit	
+	A	В	1.1	6.3	1.0	5.2	0.9	4.7	ne	
$t_{ m pd}$	В	A	1.2	6.6	1.1	5.1	0.9	4.4	ns	
4	OE	A	-	0.25	=	0.2	-	0.2	110	
t <sub>en</sub>		В	-	0.25	=	0.2	-	0.2	μs	
4	OE	A	-	0.5	-	0.4	-	035		
$t_{ m dis}$		В	-	0.5	-	0.4	-	0.35	μs	
$t_{rA}, t_{fA}$	A-port rise and fall times		0.8	3.0	0.8	3.0	0.8	3.0	ns	
$t_{rB},t_{fB}$	B-port rise and fall times		0.7	3.0	0.5	2.8	0.4	2.7	ns	
$t_{SK(O)}$		-to-channel kew	-	0.5	-	0.5	-	0.5	ns	
Max data rate			100	-	100	-	100	-	Mbps	





e.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 3.3 \pm 0.3 \,^{\circ}\text{V}$ 

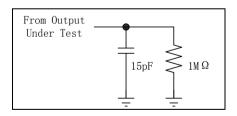
Domomotom	From	To	$V_{CCB}=3$	.3±0.3V	$V_{CCB}=$	Unit		
Parameter	(Input)	(Output)	Min	Max	Min	Max	Umt	
4	A	В	0.9	4.7	0.8	4.0	ne	
$t_{pd}$	В	A	1.0	4.9	0.9	3.8	ns	
<b>+</b>	OE	A	=	0.2	-	0.2	μs	
t <sub>en</sub>		В	-	0.2	-	0.2		
4	OE	OE	A	-	0.3	-	0.3	
$t_{ m dis}$			В	-	0.3	-	0.3	μs
$t_{rA}, t_{fA}$	A-port rise and fall times		0.7	2.8	0.7	2.8	ns	
$t_{rB}, t_{fB}$	B-port rise and fall times		0.5	2.7	0.4	2.7	ns	
t <sub>SK(O)</sub>	Channel-to-channel skew		=	0.5	-	0.5	ns	
Max data rate	-		100	=	100	=	Mbps	

**Operating Characteristics** 

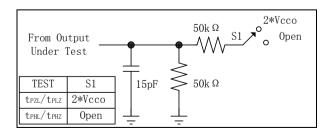
Operating characteristics										
					$ m V_{CCA}$					
			1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V	1
			V <sub>CCB</sub>							
	Parameter	Test Conditions							3.3V	Unit
			5V	1.8V	1.8V	1.8V	2.5V	5V	to	
									5.5V	
			TYP	TYP	TYP	TYP	TYP	TYP	TYP	
C	A-port input, B-port output.	$C_L=0$ , f=10 MHz,	7.8	10	9	8	8	8	9	
$C_{pdA}$	B-port input, A-port output.	$tr = t_f = 1ns,$	12	11	11	11	11	11	11	
C	A-port input, B-port output.	$OE=V_{CCA}$	38.1	28	28	28	29	30	30	
$C_{pdB}$	B-port input, A-port output.	(outputs enabled)	25.4	18	18	18	18	21	21	рE
A-port input, B-port output.		$C_L = 0$ , f = 10 MHz,	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
$C_{pdA}$	B-port input, A-port output.	$tr = t_f = 1ns,$	0.01	0.01	0.01	0.01	0.01	0.01	0.01	
C	A-port input, B-port output.	OE=GND	0.01	0.01	0.01	0.01	0.01	0.01	0.03	]
$C_{pdB}$	B-port input, A-port output.	(outputs disabled)	0.01	0.01	0.01	0.01	0.01	0.02	0.04	

### **Test Circuit**

1> Load circuit for Max data rate, pulse duration propagation delay output rise and fall time measurement



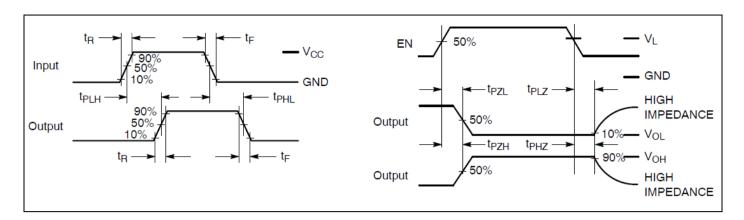
2> Load circuit for enable/disable time measurement



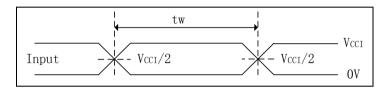
3> Timing Definitions for Propagation Delays and Enable/Disable Measurement







### 4> Voltage waveforms pulse duration



#### 5> Notes

- A. C<sub>L</sub> includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR\_10 MHz,  $Z_0 = 50$  W,  $dv/dt \ge 1$  V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as tpd.
- E.  $V_{\text{CCI}}$  is the  $V_{\text{CC}}$  associated with the input port.
- F.  $V_{\text{CCO}}$  is the  $V_{\text{CC}}$  associated with the output port.
- G. All parameters and waveforms are not applicable to all devices.





### **Principles of Operation**

### **Applications**

The PI4ULS5V104 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

#### Architecture

The PI4ULS5V104 architecture (*see Figure1*) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a dc state, the output drivers of the PI4ULS5V104 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction.

The output one shots detect rising or falling edges on the A or B ports. During a rising edge, the one shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 70  $\Omega$  at  $V_{CCO}=1.2$  V to 1.8 V, 50  $\Omega$  at  $V_{CCO}=1.8$  V to 3.3 V, and 40  $\Omega$  at  $V_{CCO}=3.3$  V to 5 V.

### **Input Driver Requirements**

Typical  $I_{IN}$  vs  $V_{IN}$  characteristics of the PI4ULS5V104 are shown in *Figure 2*. For proper operation, the device driving the data I/Os of the PI4ULS5V104 must have drive strength of at least  $\pm 2$ mA.

#### Power Up

During operation, ensure that  $V_{CCA} \le V_{CCB}$  at all times. During power-up sequencing,  $VCCA \ge VCCB$  does not damage the device, so any power supply can be ramped up first. The PI4ULS5V104 has circuitry that disables all output ports when either  $V_{CC}$  is switched off ( $V_{CCA/B} = 0$  V).

### **Enable and Disable**

The PI4ULS5V104 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time ( $t_{dis}$ ) indicates the delay between when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (ten) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

#### Pull-up or Pull-down Resistors on I/O Lines

The PI4ULS5V104 is designed to drive capacitive loads of up to 70 pF. The output drivers of the PI4ULS5V104 have low dc drive strength. If pullup or pulldown resistors are connected externally to the data I/Os, their values must be kept higher than 50 k $\Omega$  to ensure that they do not contend with the output drivers of the PI4ULS5V104.

For the same reason, the PI4ULS5V104 should not be used in applications such as I<sup>2</sup>C or 1-Wire where an open-drain driver is connected on the bidirectional data I/O.



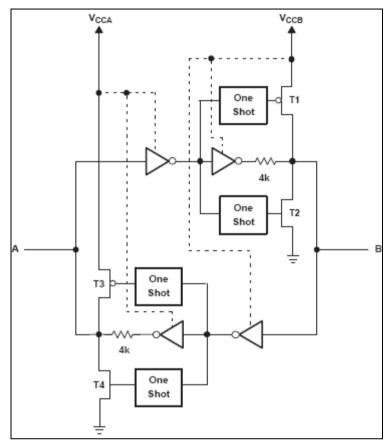


Figure 1. Architecture of PI4ULS5V104 I/O Cell

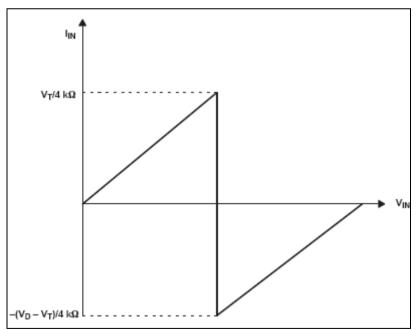


Figure 2. Typical I<sub>IN</sub> vs. V<sub>IN</sub> Curve

### Note:

A. VT is the input threshold voltage of the PI4ULS5V104 (typically  $V_{\text{CCI}} / 2)\text{.}$ 

B. VD is the supply voltage of the external driver.





# **Part Marking**

PĪ4ULS 5V104ZBE ZYYWWJG

Z: Die Rev

YYWW: Date Code (Year & Workweek)

J: Assembly Site Code G: Wafer Fab Site Code

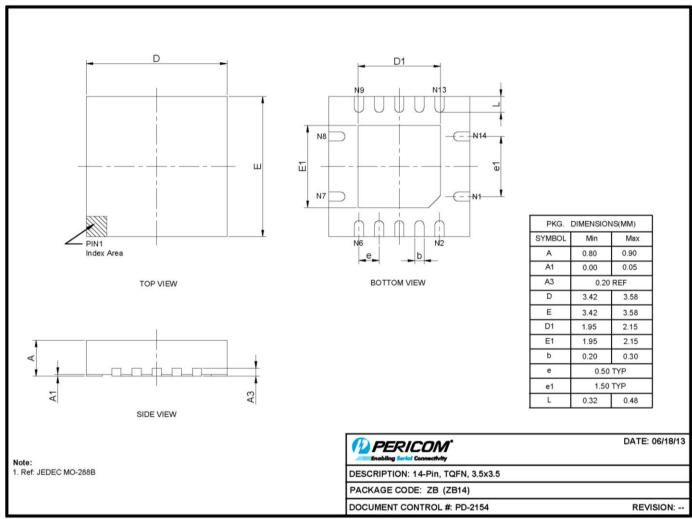
The Bar above "I" means Fab3 of MGN





### **Packaging Mechanical**

### 14-TQFN (ZB)



13-0193

### For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

### **Ordering Information**

Part Number	Package Code	Package Description
PI4ULS5V104ZBEX	ZB	14-pin, 3.5X3.5 (TQFN)

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- $_{5.}$  X suffix = Tape/Reel





October 2020

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